Tentative s	chedule updated July 14, 2008
MONDAY	AUGUST 4, 2008
PLENARY	SESSIONS
PLENARY	SESSION 1
9:00 a.m.	A.1
	Lon Bell, BSST LLC
	Addressing the Challenges of Commercializing New Thermoelectric Materials
9:30 a.m.	A.2
	Antoine Maignon, CNRS/ENSICAEN
	Thermoelectric Transition Metal Oxides: From the Search for New Materials to
	Thermoelectric Modules
10:00 a.m.	A.3
	Mercouri Kanatzidis, Northwestern University
	Nanostructured lead chalcogenides for efficient thermoelectric power generation
	applications
10:30 a.m.	Break
11.00	
11:00 a.m.	A.4 Devid Cabill University of Illinois at Urbana Champaign
	David Cahill, University of Illinois at Urbana-Champaign <i>Thermoelectric Properties of nanoscale V2-VI2 "soft superlattices"</i>
11:30 a.m.	A.5
11.30 a.m.	Sang Mock Lee, Samsung Advanced Institute of Technology
	Highly efficient thermoelectric module designs for micro-cooling and green IT
	applications
12:00	A.6
p.m.	R. Asahi, Toyota Central R&D Labs, Japan
•	Research and Development of Environmentally Amenable Thermoelectric Materials
PLENARY	SESSION 2
2:00 p.m.	A.7
	Gerald Mahan, Pennsylvania State University
	Thermoelectric Metamaterials
	A.8
2:30 p.m.	Juri Grin, Max Planck Institute for Chemical Physics of Solids
	New cage compounds and new ways of their preparation
3:00 p.m.	A.9
	Harold Böttner
	Fraunhofer-Institute for Physical Measurement Techniques <i>Thermoelectrics for high temperature differences may complement renewable energies:</i>
	A survey about state-of-the-art of so-called high temperature thermoelectric materials
3:30 p.m.	Break
5.50 p.m.	Ditak
4:00 p.m.	A.10
1	George Nolas, University of South Florida
	Structure-Property Relationships in Skutterudites, Clathrates and Other Open-
	structured Materials
4:30 p.m.	A.11
	Giulio Casati
	Universita' dell'Insurbia, Italy
	Classical and quantum transport: from Fourier law to thermoelectric efficiency

	/, AUGUST 5, 2008	
Session 1	B.a. Oxides	B.b Fundamentals/Theory
8:00 a.m.	B.a.1	B.b.1
	Ryoji Funahashi	Ravi Prasher
	National Institute of Advanced	Intel Corporation
	Industrial Science and Technology,	Thermal Transport in Nanostructured
	Japan	Materials
	Durability of thermoelectric modules	
	consisting of oxide materials	
3:30 a.m	B.a.2	B.b.2
	D. Igarashi	Tsunehiro Takeuchi
	Tohoku University	Nagoya University
	Effects of Na atom ordering on the	Unusual increase of electron thermal
	physical properties in $Na_{0.58}CoO_2$	conductivity caused by pseudogap at the
		Fermi level
:50 a.m.	B.a.3	B.b.3
u.111.	Michitaka Ohtaki	Michael Freunek
	Kyushu University	University of Freiburg
	High Thermoelectric Performance of	New Physical Model for Thermoelectric
	Dually Doped ZnO Ceramics	Generators
):10 a.m.	B.a.4	B.b.4
.10 a.m.	M. Isobe	J. Tobola
	NIMS, Tsukuba, Ibaraki Japan	AGH University of Science and Technology
	Thermoelectric Property of the One- Dimensional Metallic Cobalt Oxide	Calculations of thermopower in disordered
		thermoelectrics from electronic band
	$CaCo_2O_4$	structure with complex energy by the KKR-
20	D 7	CPA method
:30 a.m.	B.a.5	B.b.5
	S. Shibasaki	Natthapon Nakpathomkun
	Waseda University	University of Oregon
	Thermoelectric properties of B-site	Optimal balance of thermoelectric efficiency
	substituted LaRhO ₃	and power based on dimensionality
0:00 a.m.	Break	
bession 2	C.a Novel Materials	C.b Interfaces/Contacts/Modules
0:20 a.m.	C.a.1	C.b.1
	Bo Iversen	Tim Hogan
	University of Aarhus	Michigan State University
	Structure based design of new	Thermoelectric Generators Made with Novel
	thermoelectric materials	Lead Telluride Based Materials
0:50 a.m.	C.a.2	C.b.2
0.30 a.III.	C.a.2 Eric Toberer	
		Douglas T. Crane
	California Institute of Technology	BSST LLC
	Carrier concentration control in	Performance Results of a High Power
	$Yb_{14}MnSb_{11}$	Density Thermoelectric Generator: Beyond
		the Couple
1:10 a.m.	C.a.3	C.b.3
	T. J. Zhu	Mona Zebarjadi
	Zhejiang University	University of California, Santa Cruz
	Thermoelectric properties of Zintl	Effect of nano-particles on the electron and

	compounds YbZn ₂ Sb ₂ by Mn substitution in the anionic framework	thermoelectric transport
11:30 a.m.	C.a.4 Dirk Ebling Freiburg University Influence of group IV-Te-alloying on nanocomposite structure and thermoelectric properties of Bi ₂ Te ₃ Compounds	C.b.4 Hiroya Ikeda Shizuoka University Thermoelectric Characteristics of 2D Si Slab Structure on SOI Wafer
11:50 a.m.	C.a.5 J. L. Cui Ningbo University of Technology Thermoelectric properties of Cu-added Zn-Sb based alloys with multi-phase equilibrium	C.b.5 D. Ryabinin Moscow Institute of Steel and Alloys The influence of cutting technology on damaged layers depth in large-grain ingots of thermoelectric materials with grown texture
Session 3	D.a. Skutterudites/Clathrates	D.b Novel Applications
2:00 p.m.	D.a.1 Peter Rogl University of Vienna {Sr,Ba}-based clathrates Ba ₈ M _{x-y} {Si,Ge} _{46-x-y}	D.b.1 P. van der Sluis Philips Research Laboratories Eindhoven <i>Thermoelectricity applied in woodstoves for</i> <i>residential cooking</i>
2.30 p.m.	D.a.2 X. Shi General Motors R&D Center <i>Thermoelectric properties of n-type</i> <i>multiple-filled skutterudites</i>	D.b.2 V. Leonov IMEC, Leuven, Belgium Wearable thermoelectric generators for man-powered devices
2:50 p.m.	D.a.3 M. M. Koza ILL, France <i>Probing the rattling mode scenario in</i> <i>nano-cage based thermoelectric</i> <i>materials</i>	D.b.3 Zhang Qing-Jie Wuhan University Thermoelectric-photovoltaic hybrid power generation technique for solar energy utilization: scientific idea and experimental system
3:10 p.m.	D.a.4 Y. Z Pei Shanghai Institute of Ceramics High Hall Mobility of alkali-metal filled Co ₄ Sb ₁₂ thermoelectric skutterudites	D.b.4 H. Böttner Micropelt GmbH, Frieburg <i>Thermoelectric Thin Film Power Generators</i> – self-sustaining power supply for smart systems
3:30 p.m.	D.a.5 V. Ravi Jet Propulsion Laboratory, California Institute of Technology A comparative study of the mechanical behavior of some skutterudite compounds and silicon germanium alloys	D.b.5 Tsuyoshi Kajitani Tohoku University, Japan <i>Discommensuration of doped Co-121</i>
Session 4	E.a Clathrates	E.b High Power

4:20 p.m	E.a.1	E.b.1
_	Terry Tritt	Takenobu Kajikawa
	Clemson University	Shonan Institute of Technology,
	Overview of Thermoelectric Properties	Approach to the Practical use of
	of Bulk Nano-Composite	Thermoelectric Power Generation
	Thermoelectric Materials	
4:50 p.m.	E.a.2	E.b.2
	S. Stefanoski	Chris Caylor
	University of South Florida	RTI International
	Synthesis and transport properties of	High-Power Density, High Efficiency, Low-
	alkali-germanium open-framework	Profile Bulk Thermoelectric Power
	materials	Generation based on PbTe, TAGS and SiGe
5:10 p.m.	E.a.3	E.b.3
	M. Beekman	Hiroshi Nagaoyoshi
	University of South Florida	Tokyo National College of Technology
	Synthesis, structural, and physical	Development of High Efficiency MPPT
	properties of NaxSi136 clathrates	Power Conditioner and Effect of Bypass
	(0 <x<24)< td=""><td>Diode on TEG System Output</td></x<24)<>	Diode on TEG System Output

WEDNESDAY, AUGUST 6, 2008		
Session 5	F.a Bismuth Tellurides	F.b Wires
8:00 a.m.	F.a.1 Joseph Heremans The Ohio State University <i>Resonant levels and Thermopower</i>	F.b.1 Li Shi The University of Texas at Austin <i>Thermoelectric Characterization of</i>
	Enhancements in Lead-salt Semiconductors	Nanowires and Thin Films
8:30 a.m.	F.a.2 C. Andre École Polytechnique de Montréal <i>Extruded Bismuth Telluride Based N-</i> <i>type Alloys for Waste Heat</i> <i>Thermoelectric Recovery</i> <i>Applications</i>	F.b.2 T. W. Cornelius Gesellschaft für Schwerionenforschung (GSI) <i>Seebeck coefficient and electrical transport</i> <i>properties of single Bi nanowires</i>
8:50 a.m.	F.a.3 X. B. Zhao Zhejiang University Simple Synthesis Routes for Promoting Properties of Bulk Thermoelectric Materials	F.b.3 A. I. Persson University of Oregon Fabrication and thermal conductance measurements of dense and uniform InAs nanowire arrays
9:10 a.m.	F.a.4 Yanhua Zhang University of Science and Technology, Beijing <i>The microstructures and properties of</i> <i>nanostructured Bi</i> _{0.5} <i>Sb</i> _{1.5} <i>Te</i> ₃	F.b.4 Kalapi G. Biswas Purdue University Electrochemical synthesis and characterization of compositionally modulated Bi ₂ Te _{3-x} Se _x multilayered nanowire arrays
9:30 a.m.	F.a.5 Lie-Jie Wu National Tsing-Hua University <i>Effect of electric current assisted</i> <i>thermal treatment on thermoelectric</i> <i>properties of Bi-Sb-Te based</i> <i>materials prepared by powder</i> <i>metallurgy</i>	F.b.5 L. A. Konopko Institute of Electronic Engineering and Industrial Technologies, Rep. of Moldova Influence of magnetic field and doping on thermoelectric properties of Bi nanowires
Session 6	G.a Novel Materials	G.b Measurement
10:20 a.m.	G.a.1 Shinsuke Yamanaka Osaka University New Class of Advanced Thermoelectric Materials with Extremely Low Thermal Conductivity	G.b.1 Heiner Linke University of Oregon Thermoelectric efficiency and thermovoltage of a quantum-dot based energy filter
10:50 a.m.	G.a.2 Kuei-Chien Chang Industrial Technology Research Institute, Taiwan	G.b.2 M. Otani NIST Development of high-throughput power-

	The organic thermoelectric performance of poly(3,4- ethylenedioxythiophene)/poly(4- styrenesulfonate	factor and thermal conductivity screening tools for thermoelectric combinatorial library films
11:10 a.m.	G.a.3 T. Mori National Institute for Materials Science, Tsukuba Japan Doping effects of rare earth borides	G.b.3 H. Iwasaki JAIST, Japan Evaluation of Thermoelectric Properties in Mesoscopic Materials by Improved Harman Method
11:30 a.m.	G.a.4 Takashi Itoh Nagoya University Synthesis of Thermoelectric Manganese Silicide by Mechanical Alloying and Pulse Discharge Sintering	G.b.4 Qing Hao Massachusetts Institute of Technology Device Testing of Bi ₂ Te ₃ -based Thermoelectric Materials
11:50 a.m.	G.a.5 D. L. Medlin Sandia National Laboratories <i>Twin boundary defects in Bismuth</i> <i>telluride</i>	G.b.5 Mikio Koyano Japan Advanced Institute of Science and Technology Measurement of Local Peltier Constant at a Micro Contact
Session 7	H.a Tags + LAST	H.b Modules
2:00 p.m.	H.a.1 Chris Vineis Massachusetts Institute of Technology Nanostructured Thin-Film Thermoelectrics: n- and p-type PBTe/PbSe Nanodot Superlattices as a Study Case	H.b.1 Todd Anderson General Electric Global Research Manufacturability and System-Level Design of TE Modules for Automotive Waste Heat Recovery
2.30 p.m.	H.a.2 Alan J. Thompson Marlow Industries <i>Microstructure and Crystal Structure</i> <i>in TAGS Compositions</i>	H.b.2 Israel Boniche University of Florida Design and Optimization of a Miniaturized Thermoelectric Generator using Micromachined Silicon Substrates
2:50 p.m.	H.a.3 Joshua D. Sugar	H.b.3 Dirk Ebling
	Sandia National Laboratories Crystallographically Aligned Ag ₂ Te Precipitates at Multiple Length Scales in AgSbTe ₂	Fraunhofer-Institute for Physical Measurement Techniques <i>Multiphysics simulation of thermoelectric</i> <i>systems for the comparison to experimental</i> <i>device performance</i>

	AgSbTe2,GeTe	Components Optimization
3:30 p.m.	H.a.5	H.b.5
_	Vladimir Jovovic	Emil Sandoz-Rosado
	The Ohio State University	Rochester Institute of Technology
	Doping optimization of the	Experimental Characterization of
	thermoelectric properties of AgSbTe2	Thermoelectric Modules and Comparison
		with Theoretical Models for Power
		Generation
Session 8	I.a Skutterudites/Clathrates	I.b Peltier cooling
4:20 p.m.	I.a.1	I.b.1
	Mas Subramanian	Satarou Yamaguchi
	Oregon State University	Chuba University
	Thermoelectric Properties of	A New Proposal of Peltier Cooling for
	Skutterudites Filled With Duel Rattlers	Microprocessor
4:50 p.m	I.a.2	I.b.2
	S. N. Zhang	P. Y. Hou
	Clemson University	University of Washington
	Thermoelectric properties and the	Optimization of Microscale Thermoelectric
	microstructure study of TAGS-x	Cooling (TEC) Element Dimensions for Hot
		Spot Cooling Applications
5:10 p.m.	I.a.3	I.b.3
	K. Suekuni	U. Ghoshal
	Hiroshima University	Sheetak, Inc. Austin, TX
	Structure and thermoelectric	Switched Thermoelectric coolers
	properties of <i>n</i> - and <i>p</i> -type β -	
	$Ba_8Ga_{16}Sn_{30}$	

THURSDAY, AUGUST 7, 2008		
Session 9	J.a. TBA	J.b. Thin Films
8:00 a.m.	J.a.1	J.b.1
	Jeff Sharp	Rama Venkatasubramanian
	Marlow Industries	RTI International
	An Industry Perspective on	Nanoscale Thermoelectric Materials and
	Thermoelectric Power Generation	Devices
	Materials	
8:30 a.m.	J.a.2	J.b.2
	J. Martin	N. Savvides
	University of South Florida	CSIRO Materials Science and Engineering
	Enhanced thermoelectric properties	Magnetron deposition of in-situ
	in PbTe Nanocomposites	thermoelectric Mg ₂ Ge thin films
8:50 a.m.	J.a.3	J.b.3
	Y. Gelbstein	David Stokes
	Ben-Gurion University	RTI International
	Thermoelectric properties of	Thin-film Superlattice Devices for Low-
	(Pb,Sn,Ge)Te based Alloys	Temperature Energy Harvesting
9:10 a.m.	J.a.4	J.b.4
	Jong Soo Rhyee	T. S. Kamilov
	Samsung Advanced Institute of	Tashkent State Aviation Institute, Uzbekistan
	Technology, ROC	Growth Features of the Higher Manganese
	Low thermal conductivity and	Silicide Films on Silicon
	electron-hole compensation effect of	Succe I and on Succon
	the $CeTe_{2-x}Sn_x$ ($\chi CeTe_{2-x}Sn_x$ ($\chi <-$	
	$\begin{array}{c} \text{inc} & \text{corr}_{2-\chi} \text{in}_{\chi} (\chi \text{ corr}_{2-\chi} \text{in}_{\chi} (\chi \text{ or} 1 \text{ corr}_{2-\chi} \text{on}_{\chi} (\chi \text{ or} 1 \text{or} 1 \text{or} 1 \text{on}_{\chi} (\chi \text{ or} 1 \text{or} 1 o$	
9:30 a.m.	J.a.5	J.b.5
<i>J.J0</i> u.m.	Andrew May	H. Böttner
	California Institute of Technology	Fraunhofer-Institute Physical Measurement
	High Temperature Thermoelectric	Techniques, IPM, Germany
	Performance of lanthanum Telluride	Thermoelectric Properties of nanoscale V_2 -
	via Mechanical Alloying	VI3 "soft superlattices"
Session 10	K.a Advanced Materials	K.b Low-Dimensional Systems
10:20 a.m.	K.a.1	K.b.1
	Thierry Caillat	Ali Shakouri
	NASA JPL, California Institute of	University of Southern California
	Technology	Thermionic Energy Conversion Using Metal
	Development of some high-	Semiconductor Nanocomposites
	temperature thermoelectric materials	
	and components for integration into	
	advanced Radioisotope	
	Thermoelectric Generators	
10:50 a.m.	K.a.2	K.b.2
	Yoshisato Kimura	O. N. Uryupin
	Tokyo Institute of Technology	Ioffe Physical-Technical Institute, Russia
	Tokyo institute of feelinology	

	Directionally Solidified Single-Phase	in Wide Temperature Range
	Half-Heusler (Ma _{0.5} , Mb _{0.5})NiSn (Ma,	
	Mb = Hf, Zr, Ti) Alloys	
11:10 a.m.	K.a.3	K.b.3
	D. T. Morelli	Murray S. Daw
	Michigan State University	Clemson University
	High Thermoelectric Power Factor	Quantifying properties of nano-composites
	Near Room Temperature in Full	
11.00	Heusler alloys	
11:30 a.m.	K.a.4	K.b.4
	Akihiro Ishida	Jason A. Michel
	Shizuoka University, Japan	The George Washington University
	Seebeck effect in IV-VI	Synthesis of Bi2Te3 Nanocrystals by Alkalide Reduction
	<i>semiconductor films</i> and <i>quantum wells</i>	Keuucuon
Session 11	L.a Oxides	L.b Automotive and Other Applications
2:00 p.m.	L.a.1	L.b.1
_	Qiang Li	Jihui Yang
	Brookhaven National Laboratory	GM R&D Center
	Thermoelectric Materials with	Thermoelectric Materials for Automotive
	Potential High Power Factors	Applications
2.30 p.m.	L.a.2	L.b.2
	Jean-Pierre Doumerc	Atsuko Kosuga
	ICMCB-CNRS, University of	National Institute of Advanced Industrial
	Bordeaux	Science and Technology
	Layered Transition Metal Oxides for	Solid State Self-Assembly of Nanostructured-
	Thermoelectric Generation	Oxide as a Candidate for High Performance
2:50 n m	L.a.3	Thermoelectric Materials L.b.3
2:50 p.m.	L.a.5 T. Nozaki	Cronin B. Vining
	Tohoku University	ZT Services
	<i>Electronic structure and transport</i>	The Limited Role for Thermoelectronics in
	property of delafossite-type oxide	the Climate Crisis
	CuFeO ₂ system	
3:10 p.m.	L.a.4	L.b.4
-	J. E. Rodriguez	Nathan Crane
	Universidad Nacional de Columbia	University of South Florida
	Thermoelectric properties of Oxygen	Self-assembly of Microscale Thermoelectric
	deficient LaSrCuO4-x samples	Coolers for Improved Thermal Management
3:30 p.m.	L.a.5	L.b.5
	Kunio Yubuta	Paul Zschack
	Tohoku University, Japan	Argonne National Laboratory
	Excess Oxygen in Rock-Salt-Type	X-Ray Characterization of Low Thermal
	Layers of Misfit-layered Bi-based	Conductivity Thin-Film Materials at the
	Oxides	Advanced Photon Source

POSTERS

B.a Oxides	B.b Fundamentals/Theory
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Tsuyoshi Kajitani	
Tohoku University, Japan	
Discommensuration of doped Co-121	
P2	P8
Y. Cui	O. M. Løvvik
University of Waterloo, Canada	University of Oslo
Thermoelectric properties of heavily doped n-type	Novel Skutterudites for Thermoelectricity from
SrTiO ₃ bulk materials	First-Principles Calculations
P3	P9
Yiang Yang Huang	B. I. Min
CREST Japan Science and Technology Agency	POSTECH, Korea
Crystal Structure and High Temperature	Thermoelectric power in the magnetic polaron
Thermoelectric Properties of	system
$Ca_{0.96-x}Sr_xBi_{0.04}Mn_{0.96}V_{0.04}O_3$	
(x = 0, 0.1, 0.3 and 0.5)	
P4	P10
A. Hirahara	
Waseda University, Japan	
Thermoelectric Properties of Zn Substituted	
Magnetite	
P5	
Li Zhang	
Wuhan University of Technology	
A novel and simple route to the synthesis of	
preferred-orientated preferred oriented γ -	
$Na_{x}Co_{2}O_{4}$ crystals	
P6	
F. Kawshima	
Tohoku University, Japan	
High temperature thermoelectric properties of	
layered oxide	
$C_{,Bi}MnO_{4}$	
P7	
Y. Klein	
Waseda University	
Transport properties and cationic substitutions in	
Sr_2IrO_4	
C.a Novel Materials	Ch Interforms/Contracts/Madulas
	C.b Interfaces/Contacts/Modules
P11 C V Harris	P20 Martin Diana
CK. Huang	Martin Riggs
California Institute of Technology	Moscow State Technical University
A Study of P-type Yb ₁₄ MnSb ₁₁ for High	Thermoelectric modules reliability improvement
Temperature Thermoelectric Applications	methods
P12	P21
B.c.7	Yen-Chun Huang

F. Gascoin	National Tsing-Hua University, Taiwan A study of
Universite' Montpellier	interfacial reaction between molten Sn-Ag solder
Complex Antimonides as thermoelectric	and Te substrate
Materials: Preparation and transport properties of	
Yb_4Sb_3	
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Takashi Ueda	
Shimane University, Japan	
Influence of impurity element on β - Zn4Sb3	
thermoelectric materials	
P14	P23
J.E. Rodriguez	Minehiro Tonosaki
Universidad Nacional de Columbia	Sony Corporation, Japan
Solid-state synthesis of multi-phase Zn ₄ Sb ₃	<i>Effect of protective layer and etch process for</i>
polycrystalline samples	silicon molded micro Peltier array
P15	Patricia Gilbert
Catherine Cox	Marlow Industries
University of California, Davis	Metal Contacts for TAGS-85
High Temperature Heat Capacity Measurements	
and Thermoelectric Performance	
of $Yb_{14}Mn_{1-x}Al_xSb_{11}$	
P16	
Japheth F. Rauscher	
University of California, Davis	
A Comparative Study of Synthetic Routes to	
Coped Yb ₁₄ MnSb ₁₄	
P17	
Su "Ike" Chi	
California Institute of Technology	
Synthesis of Yb ₁₄ MnSb ₁₄ Zintl Compound by a	
Melt Process	
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Sabah K. Bux	
University of California, Los Angeles	
Thermal Conductivity of Nanostructured Bulk	
III-V Semiconductors	
P19	
Krzysztof Gofryk	
Institute for Transuranium Elements	
Thermoelectric Perfomance of Strongly	
Correlated Compounds RPd3(R=Ce, U, Np, Pu)	
Tanghong Yi	
University of California, Davis	
Synthesis and investigation of Yb ₁₁ InSb ₉ and	
<i>Yb</i> ₁₁ <i>GaSb</i> ₉ for thermoelectric applications	
D.a Skutterudites/Clathrates	D.b Novel Applications
P24	P38 Li Peng
JY. Jung	Wuhan University
Chungju National University, Korea	A solar hybrid generation system utilizing both
Synthesis and Thermoelectric Properties of	concentrator solar cell and thermoelectric

In _z Co ₄ Sb ₁₂ Skutterudites	generator
P25	P39
JY. Jung	C. Lertsatitthanakorn
8	
Chungju National University, Korea	Mahasarakham University, Thailand
Electronic Transport Properties of In-filled	Performance studies on a hybrid thermoelectric
CoSb ₃ Skutterudites	solar air collector
P26	P40
W. Y. Zhao	K. Shimizu
Wuhan University of Technology, China	Nagaoka University of Technology, Japan
Effect of Ni on thermoelectric properties of	Performance Improvement of flexible
barium and indium double-filled skutterudites	thermoelectric device: FEM-based simulation
P27	P41
Zhong-wei Ruan	V. Leonov
Wuhan University of Technology, China	IMEC, Leuven, Belgium
Influence of inclusions on the Surface	Thermal shunts in thermoelectric energy
Mechanical Behavior of CoSb ₃ based	scavengers
Skutterudite Compounds	
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Peng-Fei Wen	
Wuhan University of Technology, China	
Effect of Cyclic Thermal Loading on the	
Microstructures and Thermoelectric Properties of	
CoSb ₃	
P29	
Li Yao	
Wuhan University of Technology	
Effect of high pressure sintering process on the	
microstructure and thermoelectric properties of	
CoSb ₃	
P30	
Li-sheng Liu	
Wuhan University of Technology, China	
<i>Electronic structure of CoSb₃ filled with double-</i>	
atoms (Ba and In)	
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J. Y. Peng	
Clemson University	
Synthesis and thermoelectric properties of	
$In_x Yb_{01} Co_4 Sb_{12}$ Skutterudites	
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Ramesh Chandra Mallik	
German Aerospace Center Thermoelectric Properties of Partially In Filled	
Thermoelectric Properties of Partially In Filled	
and Over-Filled Co ₄ Sb ₁₂ Skutterudite Material	
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Han Li	
Wuhan University of Technology, China	
The effects of pre-annealing on microstructure of	
<i>Yb filled CoSb₃ skutterudites prepared by rapid</i>	
solidification	

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J. Yang	
General Motors R&D Center	
Electrical transport properties of filled CoSb ₃	
skutterudites: a theoretical study	
P35	
Qiyin Lin	
University of Oregon	
Controlling Carrier Concentration in the Misfit	
Layered Compound [(PbSe) _{0.99}] ₁ (WSe ₂) ₁	
P36	
Qiyin Lin	
University of Oregon	
Synthesis and thermoelectric properties of	
pseudo-binary skutterudite $CoGe_{1.5-\delta}Se_{1.5-\delta}$ and	
$CoSn_{1.5-\delta}Te_{1.5-\delta}$	
COSH1.5-81 C1.5-8	
A. Grytsiv	
University of Vienna	
Dynamical Response of NdFe ₄ Sb ₁₂ and CoSb ₃	
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P. Poinas	
European Space Agency, ESTEC	
Role of Ni in Indium Partially Filled Skutterudite	
Compounds	
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	E.b High Power P49
E.a Clathrates	
E.a Clathrates P42 X. Shi	P49 Kevin Smith
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E.a Clathrates P42 X. Shi General Motors R&D Center Thermoelectric properties of Ba ₈ TM ₄ Ge ₄₂ -based	P49 Kevin Smith Rochester Institute of Technology <i>Experimental Validation of a Thermoelectric</i>
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